



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Eliyahou Harari et al.
Title: Non-Volatile Memory Cells Utilizing Substrate Trenches
Application No.: 09/925,134 Filing Date: August 8, 2001
Examiner: Quinto, Kevin V. Group Art Unit: 2826
Docket No.: SNDK.111US1 Conf. No.: 6957

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, Applicant(s) call(s) the documents listed on the enclosed Form PTO-1449 to the Examiner's attention in this patent application. Copies of the documents listed on the accompanying Form PTO-1449 are enclosed.

Citation of these documents shall not be construed as (1) an admission that the documents are prior art with respect to the invention or inventions claimed in this application, (2) a representation that a search has been made (other than as indicated by any cited document), or (3) an admission that the cited information is, or is considered to be, material to patentability as defined in § 1.56(b).

This information disclosure statement is submitted under 37 C.F.R. § 1.97(b) and consequently no fee should be required. The Commissioner is authorized, however, to charge

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Respectfully submitted,



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| U.S. Department of Commerce, Patent and Trademark Office | | | | Atty Docket No. | | Serial No. | | |
| | | | | M-10237-1P US | | 09/92134 | | |
| INFORMATION DISCLOSURE STATEMENT BY APPLICANT | | | | Applicant(s) | | | | |
| (Use several sheets if necessary) | | | | Eliyahou Harari; Jack H. Yuan; George Samachisa, Henry Chien. | | | | |
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| *EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant. | | | | | | | | |